

TEA1832TS

GreenChip SMPS control IC

Rev. 1 — 16 December 2014

Product data sheet

1. General description

The TEA1832TS is a low-cost Switched Mode Power Supply (SMPS) controller IC intended for flyback topologies. The TEA1832TS operates in peak current and frequency control mode. Frequency jitter has been implemented to reduce ElectroMagnetic Interference (EMI). Slope compensation is integrated for Continuous Conduction Mode (CCM) operation.

The TEA1832TS IC features OverPower Protection (OPP). The controller accepts an overpower situation up to 200 % for a limited amount of time.

Mains undervoltage protection (brownin/brownout), output OverVoltage Protection (OVP), and OverTemperature Protection (OTP) can be implemented using a minimal number of external components.

At low-power levels, the primary peak current is set to 22 % of the maximum peak current. The switching frequency is reduced to limit the switching losses. The combination of fixed frequency operation at high output power and frequency reduction at low output power provides high efficiency over the total load range.

The TEA1832TS makes the design of low-cost, highly efficient and reliable supplies easier by requiring a minimum number of external components. The device is especially suited for medium power applications.

2. Features and benefits

- SMPS controller IC enabling low-cost applications
- Large input voltage range (10.5 V to 36 V)
- Integrated OverVoltage Protection (OVP) on the VCC pin
- Accurate OverVoltage Protection (OVP) via the ISENSE pin
- Dedicated burst mode, allowing a low VCC capacitor value
- Very low supply current during start-up and restart (11 μA typical)
- Low supply current during normal operation (0.58 mA typical without load)
- Adaptive internal overpower time-out
- Overpower protection including high/low line compensation
- Fixed switching frequency with frequency jitter to reduce EMI
- Frequency reduction with fixed minimum peak current to maintain high efficiency at low output power levels
- Peak power operation up to 200 % by frequency increase and peak current increase
- Slope compensation for CCM operation



- Integrated soft-start
- Drive capability 300 mA source, 750 mA sink
- Maximum duty cycle set at 90 %
- Mains undervoltage protection (brownin/brownout)
- Output Short Circuit Protection (OSCP), avoiding transformer saturation
- External OverTemperature Protection (OTP)
- IC overtemperature protection
- Internal VCC OVP, external OVP, internal OTP, and external OTP are latched protections; all other protections cause a restart

3. Applications

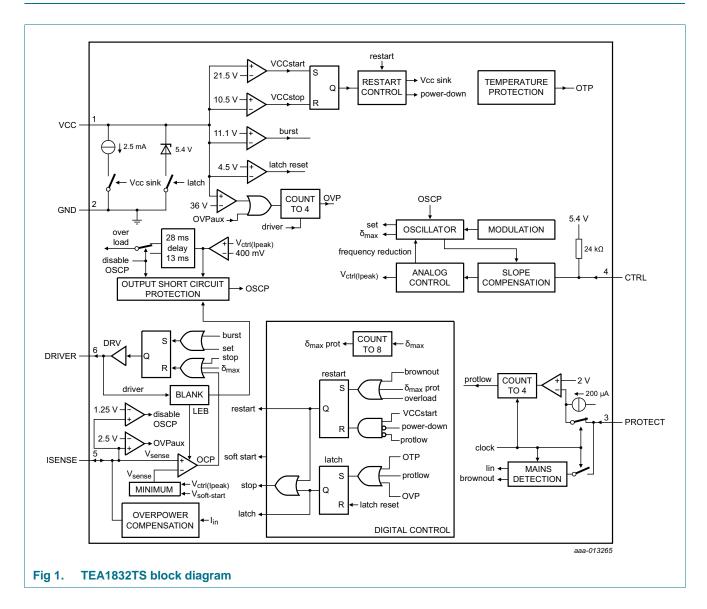
All applications that require an efficient and cost-effective power supply solution. The TEA1832TS is especially suited for medium power applications.

4. Ordering information

Table 1. Ordering information

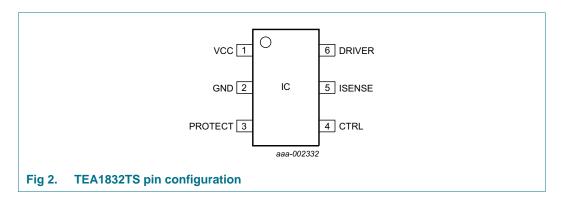
Type number	Package					
	Name	Description	Version			
TEA1832TS/1	TSOP6	plastic surface-mounted package; 6 leads	SOT457			

5. Block diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

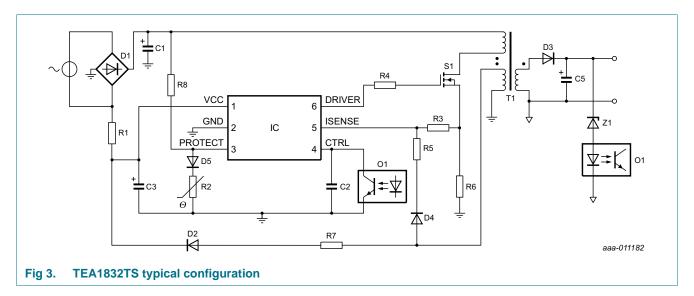
Table 2. Pin description

Symbol	Pin	Description
VCC	1	supply voltage
GND	2	ground
PROTECT	3	protection and mains detect input
CTRL	4	control input
ISENSE	5	current sense and accurate OVP input
DRIVER	6	gate driver output

7. Functional description

7.1 General control

The TEA1832TS contains a controller for a flyback circuit. A typical configuration is shown in Figure 3.



7.2 Start-up and UnderVoltage LockOut (UVLO)

Initially, the capacitor on the VCC pin, C3, is charged from the high-voltage mains via resistor R1.

As long as the voltage on the VCC pin is below $V_{startup}$, the IC current consumption is low (11 μ A typical). When the voltage on the VCC pin reaches $V_{startup}$, the IC first checks the PROTECT pin. Only when the current exceeds the brownin level ($I_{mains(bi)}$) during mains detect and the voltage surpasses $V_{det(PROTECT)}$ during external OTP measurement the IC starts switching. An internal soft-start time of 3.5 ms allows the ISENSE peak voltage to increase gradually to prevent audible noise. In a typical application, the auxiliary winding of the transformer takes over the supply voltage.

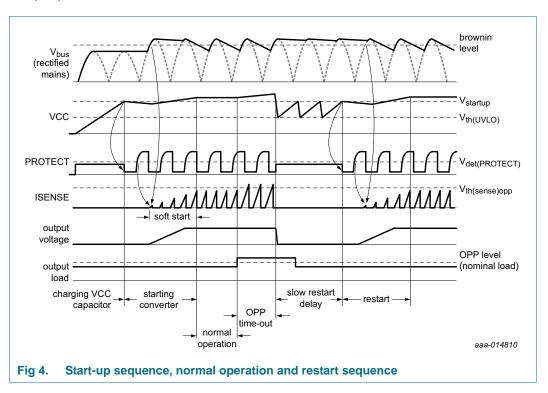
If a protection is triggered, the controller stops switching. Depending on the protection triggered, it either causes a restart or latches the converter to an off-state.

The OPP, UVLO, brownin/brownout, maximum duty cycle protections cause a safe restart. The internal and external OVP and the internal and external OTP latch the converter to an off-state.

A restart protection disables the switching of the IC. The supply voltage of the IC drops to the UVLO level. When the UVLO level is reached, the IC switches to Power-down mode, where it consumes a low supply current (11 μ A typical). The VCC capacitor is recharged via R1 until the VCC start-up level is reached. The IC starts switching again.

The OPP protection performs a slow restart to lower the average input power during a fault condition. The restart sequence that discharges and recharges the VCC capacitor is performed three times, before switching recommences (see Figure 4).

When a latched protection is triggered, the TEA1832TS immediately enters power-down mode. The VCC pin is clamped to a voltage just above the latch protection reset voltage $(V_{rst(latch)} + 1 V)$.



When the voltage on pin VCC drops below the $V_{th(UVLO)}$ level during normal operation, the controller stops switching. The TEA1832TS waits for the rectified mains to charge the VCC pin to $V_{startup}$ using resistor R1.

7.3 Supply management

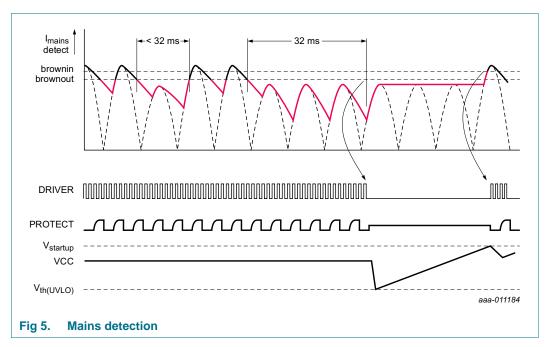
All internal reference voltages are derived from a temperature compensated on-chip band gap circuit. Internal reference currents are derived from a trimmed and temperature compensated current reference circuit.

7.4 External overtemperature protection and mains detect input (pin PROTECT)

The PROTECT input combines the functions of the mains voltage detection (browin/brownout) and the external OverTemperature Protection (OTP). An internal clock separates the period of measuring the mains voltage and the period of detecting external OverTemperature Protection (OTP). In a typical application, the PROTECT pin is connected to the mains via a resistor. It is connected to ground via a negative temperature coefficient (NTC) thermistor and a diode.

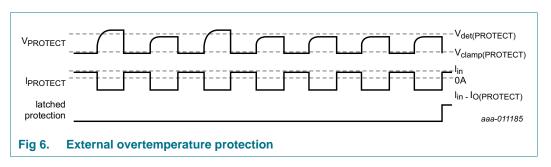
When measuring the mains voltage, the PROTECT pin is regulated to 0.25 V to prevent that the external diode conducts current. The current into the PROTECT pin is measured and stored. Once the measured current is above the brownin level, the system is allowed to start switching. If the mains voltage is continuously below the brownout level for at least 32 ms, a brownout is detected. The system immediately stops switching and performs a restart. The VCC capacitor is discharged to the UVLO level and then charged to V_{startup}

once before switching recommences (See Figure 5).



When detecting the external temperature, a current of 200 μ A (typical) out of the PROTECT pin flows through the external capacitor and the NTC thermistor. If the PROTECT voltage at the end of the measuring period is below $V_{\text{det}(PROTECT)}$ for four consecutive measuring cycles, the IC detects overtemperature. It activates a latched protection.

The offset due to the current from the mains is canceled internally by remembering the sinking current I_{in} when measuring the mains voltage (See <u>Figure 6</u>). The stored current is also used as the input of high/low line compensation.



An internal clamp of 4.1 V (typical) protects this pin from excessive voltages.

7.5 Duty cycle control (pin CTRL)

Pin CTRL regulates the output power of the converter. This pin is connected to an internal voltage source of 5.4 V via an internal resistor (typical resistance: $26 \text{ k}\Omega$).

The CTRL pin voltage sets the peak current which is measured using the ISENSE pin (see Section 7.8). At low output power, the switching frequency is reduced (see Section 7.12). The maximum duty cycle is limited to 90 % (typical).

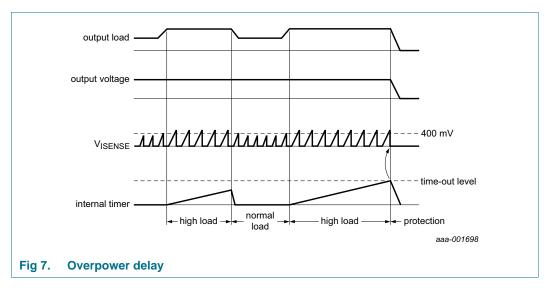
After eight consecutive converter strokes at maximum duty cycle, the restart protection is activated. In a restart, the VCC capacitor is quickly discharged to the $V_{th(UVLO)}$ level and recharged to the start-up level from the high-voltage mains, before switching recommences.

7.6 Slope compensation (pin CTRL)

A slope compensation circuit is integrated for CCM. The slope compensation guarantees stable operation for duty cycles exceeding 50 %.

7.7 Overpower timer

A temporary overload situation is allowed. If V_{sense} (see <u>Figure 1</u>) set by pin CTRL exceeds 400 mV, an internal timer is started. If the overload situation continues to exist for more than 27.5 ms (typical), an OverPower Protection (OPP) is triggered (see <u>Figure 7</u>).

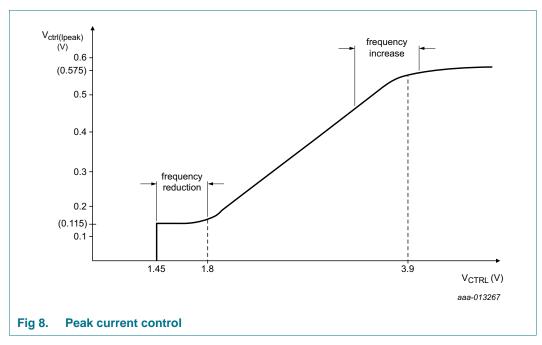


The TEA1832TS enters the overpower restart mode when the overload time-out is reached. In overpower restart mode, the VCC capacitor is discharged to UVLO level and then charged to the start-up level three times before the converter switches again.

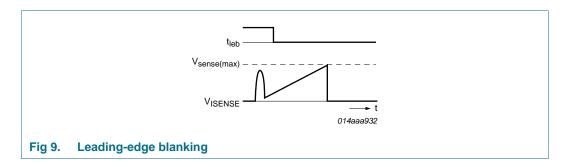
7.8 Current mode control (pin ISENSE)

Current mode control is used because it ensures a good line regulation.

Pin ISENSE senses the primary current across external resistor R6 and compares it with an internal control voltage. The internal control voltage is proportional to the CTRL pin voltage (see Figure 8).



Leading-edge blanking prevents false triggering due to capacitive discharge when switching on the external power switch (see Figure 9).



7.9 Overvoltage protection (pin ISENSE)

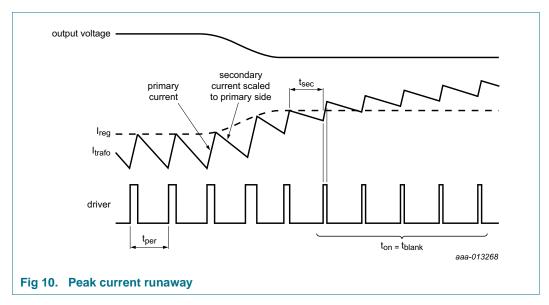
Accurate overvoltage protection can be realized at the ISENSE pin by sensing the auxiliary voltage. During the primary stroke, diode D4 (see <u>Figure 3</u>) is blocked so that the converter still works under current mode control. During the secondary stroke, the ISENSE voltage represents the output voltage via the resistor divider R5 and R3 (see <u>Figure 3</u>). The ISENSE voltage is sampled 2 μ s after the gate signal drops to avoid the ringing of the transformer. If the sampled voltage exceeds $V_{\text{ovp(ISENSE)}}$ for four consecutive switching cycles, the IC triggers the latched protection.

7.10 Overvoltage protection (pin VCC)

An OverVoltage Protection (OVP) circuit is connected to the VCC pin. When the V_{CC} exceeds $V_{th(OVP)}$ (36 V typical) for four consecutive switching cycles, the IC triggers the latched protection. When V_{CC} drops below $V_{th(OVP)}$ before count = 4 is reached, the counter is reset to zero.

7.11 Output Short Circuit Protection (OSCP)

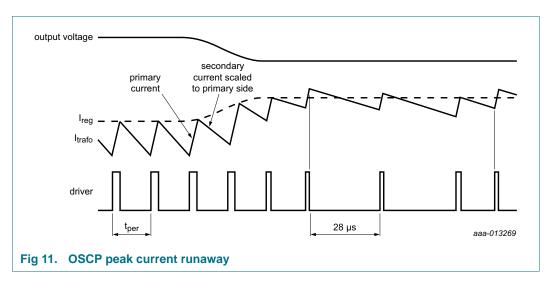
A flyback controller operating in CCM at a fixed frequency turns on the primary MOSFET after a predefined period (see Figure 10). The minimum on-time equals the blanking time. If after the blanking time the measured peak current (V_{ISENSE}) is higher than the I_{peak} regulation level, the driver is switched off.



The output voltage can drop, for instance, because a load is too high or a short circuit event occurs. If the output voltage drops, the decrease of the transformer current during the secondary stroke time (t_{sec}) becomes less. As a result, the next cycle starts at a higher peak current.

Also, at the next cycle, the minimum on-time equals the blanking time. During this blanking time, the peak current can increase to above the targeted regulation level. If the transformer current does not decrease sufficiently during the secondary stroke, the peak current can continuously increase to such a level that the transformer saturates (see Figure 10).

To avoid this continuous peak current increase, also called runaway, the IC features a special protection (see Figure 11).



If the system detects that the peak current already exceeds the targeted level after 1 μ s, the next switching period time is extended from 7.7 μ s (f_{sw} = 130 kHz) to 28 μ s (f_{sw} = 36 kHz). The time of the secondary stroke is then sufficient to decrease the transformer current to below the targeted peak current again.

To avoid activation at low loads, the OSCP is only enabled when the overpower timer is active. Additionally, to avoid activation during peak power, V_{out} must be below half the OVP level.

The V_{out} level is measured on the ISENSE pin in a similar way the overvoltage protection is measured.

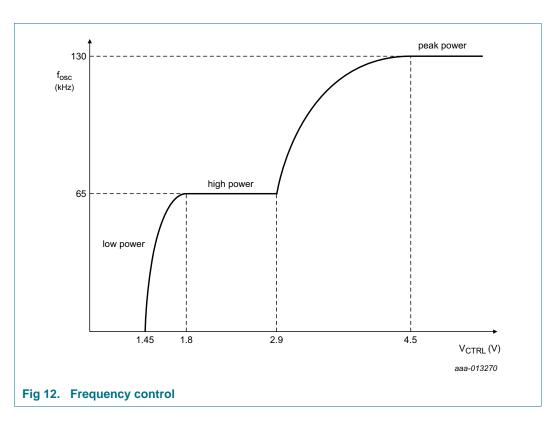
To limit the input power during a short circuit or an overload event, the OPP time is reduced to 50 % when OSCP is enabled.

7.12 Peak power, high-power and low-power operation

During high-power operation, with the converter running at a 65 kHz (typical) fixed frequency, the power is controlled by varying the peak current. A peak power mode is implemented to supply a short overload situation. In peak power mode, both frequency and peak current are increased.

In low-power operation, switching losses are reduced by lowering the switching frequency.

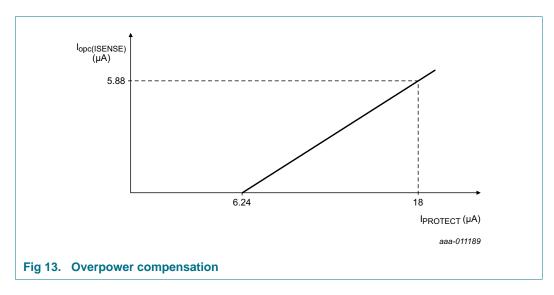
The switching frequency of the converter is reduced while the peak current is set to 22 % of the maximum peak current (see <u>Figure 8</u> and <u>Figure 12</u>).



7.13 Overpower or high/low line compensation

The overpower compensation function can be used to realize a maximum output power which is nearly constant over the full input mains. The overpower compensation circuit measures the mains detect input current on the PROTECT pin and outputs a proportionally dependent current on the ISENSE pin. The DC voltage across resistor R3 (see Figure 3) limits the maximum peak current on the current sense resistor (see Figure 13).

At low output power levels, the overpower compensation circuit is switched off.



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7.14 Burst mode

If the CTRL voltage (V_{CTRL}) is < 1.45 V, the system is not switching. It waits until the V_{CTRL} exceeds this minimum level before starting the next cycle. During this period, the TEA1832TS discharges the primary VCC capacitor. If the voltage on the VCC pin then drops to below the burst threshold level ($V_{th(burst)}$), the system asserts two DRIVER pulses to recharge the VCC capacitor. The assertion avoids that the voltage on the VCC pin drops to below the UVLO level during a large off-time.

Worst off-time occurs when there is a load transient from peak load to no-load. The output voltage shows an overshoot and stops switching until the output voltage drops to below the regulation level while there is no-load at the output.

For minimum no-load input power, the chosen value of the external capacitor at the VCC pin must be high enough to prevent that the voltage on the VCC pin drops below the burst threshold level at continuous no-load operation. The burst mode is only intended to assist at load changes until the output voltage drops to below the regulation level while there is no-load at the output.

7.15 Driver (pin DRIVER)

The driver circuit to the gate of the power MOSFET has a current sourcing capability of typically 300 mA and a current sink capability of typically 750 mA. These capabilities enable a fast turn-on and turn-off of the power MOSFET for efficient operation.

7.16 OverTemperature Protection (OTP)

If the junction temperature exceeds the thermal shutdown limit, integrated overtemperature protection ensures that the IC stops switching.

OTP is a latched protection. It can be reset by removing the voltage on pin VCC.

8. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Voltages			·	·	
V _{CC}	supply voltage		-0.4	+40	V
V _{PROTECT}	voltage on pin PROTECT	current limited	-0.4	+5	V
V _{CTRL}	voltage on pin CTRL		-0.4	+5.5	V
V _{ISENSE}	voltage on pin ISENSE	current limited to 2 mA	-0.7	+5	V
Currents			,		
I _{VCC}	current on pin VCC	δ < 10 %	-	0.4	Α
I _{I(PROTECT)}	input current on pin PROTECT		-1	+1	mA
I _{CTRL}	current on pin CTRL		-3	0	mA
I _{ISENSE}	current on pin ISENSE		-10	+0.5	mA
I _{DRIVER}	current on pin DRIVER	δ < 10 %	-0.4	+1	Α

 Table 3.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
General					"
P _{tot}	total power dissipation	T _{amb} < 75 °C	-	0.29	W
T _{stg}	storage temperature		-55	+150	°C
Tj	junction temperature		-40	+150	°C
ESD					
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM)			
		JEDEC class 2; all pin	-2500	+2500	V
		Charged Device Model (CDM)			
		JEDEC class 3; all pins	-750	+750	V

9. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air; single layer JEDEC test board	259	K/W
R _{th(j-c)}	thermal resistance from junction to case	in free air; JEDEC test board	152	K/W

10. Characteristics

Table 5. Characteristics

 T_{amb} = 25 °C; V_{CC} = 20 V; all voltages are measured with respect to ground (pin 2); currents are positive when flowing into the IC; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Supply voltage	management (pin VC	C)	•				
V _{startup}	start-up voltage			20	22	24	V
$V_{th(UVLO)}$	undervoltage lockout threshold voltage			9.4	10.5	11.6	V
V _{hys}	hysteresis voltage	V _{startup} - V _{th(UVLO)}		8.5	11.5	14.5	V
V _{th(burst)}	burst mode threshold voltage			-	11.1	-	V
$\Delta V_{ ext{th(burst-UVLO)}}$	burst mode to UVLO threshold voltage difference	$V_{th(burst)} > V_{th(UVLO)}$	[1]	0.5	0.6	0.7	V
V _{rst(latch)}	latched reset voltage			3.5	4.5	5.5	V
V _{clamp(VCC)}	clamp voltage on pin VCC	latched protection mode; $I_{CC} = 15 \mu A$		V _{rst(latch)} + 1	-	-	V
		latched protection mode; $I_{CC} = 500 \mu A$		-	-	V _{rst(latch)} + 4	V

TEA1832TS

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 Table 5.
 Characteristics ...continued

 T_{amb} = 25 °C; V_{CC} = 20 V; all voltages are measured with respect to ground (pin 2); currents are positive when flowing into the IC; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CC(startup)}	start-up supply current	V _{CC} < V _{startup}		6	11	16	μΑ
I _{CC(oper)}	operating supply current	no-load on pin DRIVER; δ = 2 %; excluding opto current		-	0.58	-	mA
		no-load on pin DRIVER; δ = 25 %, excluding opto current		-	0.62	-	mA
I _{CC(restart)}	restart supply current			1	2.5	-	mA
Protection inpu	it (pin PROTECT)				1		'
V _{det(PROTECT)}	detection voltage on pin PROTECT	$I_{I(PROTECT)} = -200 \mu A$		1.95	2	2.05	V
I _{O(PROTECT)}	output current on pin PROTECT	$V_{PROTECT} = V_{det(PROTECT)}$		-212.5	-200	-187.5	μΑ
V _{clamp(PROTECT)}	clamp voltage on pin PROTECT	$I_{I(PROTECT)} = 6 \mu A;$ mains detect period; $C_{max(PROTECT)} = 10 \text{ pF}$		205	260	315	mV
		I _{I(PROTECT)} ≥ −200 μA; OTP measurement period	[2]	3.5	4.1	4.7	V
Mains detect (p	in PROTECT)			1			-
I _{mains(bi)}	mains brownin current			5.28	5.7	6.12	μΑ
I _{mains(bo)}	mains brownout current			4.63	5.0	5.37	μΑ
Peak current co	ontrol (pin CTRL)			1			'
V _{CTRL}	voltage on pin CTRL	for minimum flyback peak current		1.5	1.8	2.1	V
		for maximum flyback peak current		3.4	3.9	4.3	V
R _{int(CTRL)}	internal resistance on pin CTRL			20	26	32	kΩ
I _{O(CTRL)}	output current on pin CTRL	V _{CTRL} = 1.4 V V _{CTRL} = 3.7 V		-183 -67.5	-138 -50	-93 -32.5	μA μA
Pulse width mo	dulator	VCIRL - 0.7 V		07.0	00	02.0	pu t
f _{osc}	oscillator frequency	OSCP		29	36	43	kHz
-030		peak power		118	130	142	kHz
		high power		60.5	65	69.5	kHz
f _{mod}	modulation frequency			195	260	325	Hz
Δf_{mod}	modulation frequency variation	high power		±3	±4	±5	kHz
δ_{max}	maximum duty cycle			86	90	94	%

 Table 5.
 Characteristics ...continued

 T_{amb} = 25 °C; V_{CC} = 20 V; all voltages are measured with respect to ground (pin 2); currents are positive when flowing into the IC; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$N_{cy(dmax)}$	number of switching cycles with maximum duty cycle		7	-	8	
V _{start(red)f}	frequency reduction start voltage	pin CTRL dropping to low power	1.5	1.8	2.1	V
V _{start(incr)f}	frequency increase start voltage	pin CTRL	2.6	2.9	3.2	V
$V_{M(f)max}$	maximum frequency peak voltage	pin CTRL	4.2	4.5	4.8	V
$V_{\delta(zero)}$	zero duty cycle voltage	pin CTRL	1.15	1.45	1.75	V
Overpower pro	otection			'		'
t _{to(opp)}	overpower protection time-out time		20.5	27.5	34.5	ms
Current sense	and overpower compe	ensation (pin ISENSE)		'		'
V _{sense(max)}	maximum sense voltage	$\Delta V/\Delta t = 0 \text{ V/s}$	0.555	0.590	0.625	V
t _{PD(sense)}	sense propagation delay		130	155	180	ns
V _{th(sense)opp}	overpower protection sense threshold voltage		370	400	430	mV
$\Delta V_{ISENSE}/\Delta t$	slope compensation voltage on pin ISENSE	high-power mode	-	18	-	mV/μs
t _{leb}	leading edge blanking time		275	325	375	ns
I _{opc(ISENSE)}	overpower compensation	I _{PROTECT} = 10 μA; V _{ctrl(lpeak)} > 400 mV	-1.5	-2	-2.5	μΑ
	current on pin ISENSE	I _{PROTECT} = 18 μA; V _{ctrl(lpeak)} > 400 mV	-5.5	-6	-6.5	μΑ
Soft start (pin	ISENSE)		<u> </u>		'	'
t _{start(soft)}	soft start time		2.7	3.5	4.2	ms
Driver (pin DR	IVER)					
I _{source(DRIVER)}	source current on pin DRIVER	V _{DRIVER} = 2 V	-	-0.3	-0.25	А
I _{sink(DRIVER)}	sink current on pin	V _{DRIVER} = 2 V	0.25	0.3	-	А
	DRIVER	V _{DRIVER} = 10 V	0.6	0.75	-	Α
V _{O(DRIVER)max}	maximum output voltage on pin DRIVER		9	10.5	12	V
Overvoltage p	rotection (pins VCC an	d ISENSE)	1			-
V _{ovp(VCC)}	overvoltage protection voltage on pin VCC		34.8	36	37.2	V

Table 5. Characteristics ... continued

 T_{amb} = 25 °C; V_{CC} = 20 V; all voltages are measured with respect to ground (pin 2); currents are positive when flowing into the IC; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{ovp(ISENSE)}	overvoltage protection voltage on pin ISENSE		2.4	2.5	2.6	V
t _{blank(ovp)} ISENSE	overvoltage protection blanking time on pin ISENSE		1.7	2.1	2.5	μS
N _{cy(ovp)}	number of overvoltage protection cycles		4	4	4	
Output short c	ircuit protection		1		,	
V _{dis(oscp)} ISENSE	output short circuit protection disable voltage on pin ISENSE	OSCP is disabled when V _{ISENSE} exceeds V _{dis(oscp)} SENSE	1.2	1.25	1.3	V
t _{to(oscp)}	output short circuit protection time-out time		10	14.5	19	ms
Temperature p	rotection		1	1		-
$T_{pl(IC)}$	IC protection level temperature		130	140	150	°C

^[1] Guaranteed by design.

^[2] The clamp voltage on the PROTECT pin is lowered when the IC is in Power-down mode. (latched or restart protection).

^[3] The Output Short Circuit Protection (OSCP) is only enabled when the voltage level on the ISENSE pin during the secondary stroke is below $V_{dis(oscp)|SENSE}$ level (half the $V_{ovp(ISENSE)}$ level). When enabled, the OSCP becomes active when the V_{sense} level exceeds $V_{th(sense)opp}$ and the V_{sense} level is reached within 1 μs (cycle-by-cycle). The switching period is then stretched to 28 μs (36 kHz, f_{osc} OSCP).

11. Application information

A power supply with the TEA1832TS is a flyback converter which operates in both Discontinuous Conduction Mode (DCM) and Continuous Conduction Mode (CCM). Which mode depends on the input voltage and output power.

Resistor R1 charges the small buffer capacitor C3 at start-up. The auxiliary winding takes over during normal operation.

The driver pin switches the MOSFET. Resistor R4 is added to protect the driver against switching spikes due to parasitics (inductance and capacitance of tracks, MOSFET, and transformer).

Resistor R6 converts the MOSFET current to a voltage. It is measured on the ISENSE pin. The R6 value determines the maximum primary peak current through the MOSFET.

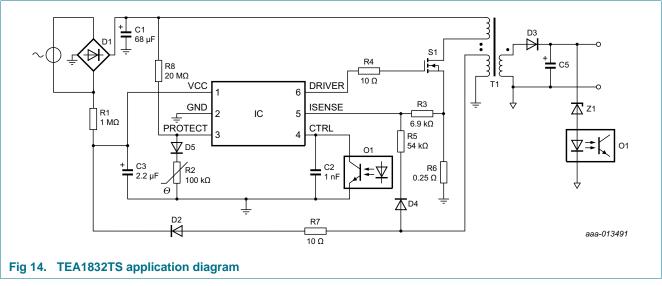
The measured peak current is compensated for the mains input voltage using a current through resistor R3 that is proportional to the bus voltage of capacitor C1. During the secondary stroke, the auxiliary voltage is measured using diode D4 and resistors R5, R3, and R6. The measured value can be used for an overvoltage protection for the output voltage.

Place capacitor C2 close to the CTRL pin to suppress noise.

The PROTECT pin cycles between mains voltage detect and external overtemperature measurement. During mains voltage detection, the current through resistor R8 is measured. This current relates to the voltage on capacitor C1 and the input voltage. The current is used to realize brownin, brownout, and input voltage compensation for the overpower protection.

During overtemperature protection, a current is sourced from the pin. The voltage over diode D5 and NTC resistor R2 is measured. A fixed comparator level detects when the NTC value drops too much.

To avoid pickup of disturbance, place both resistor R8 and diode D5/resistor R2 as close as possible to the pin.



TEA1832TS

12. Package outline

Plastic surface-mounted package (TSOP6); 6 leads

SOT457

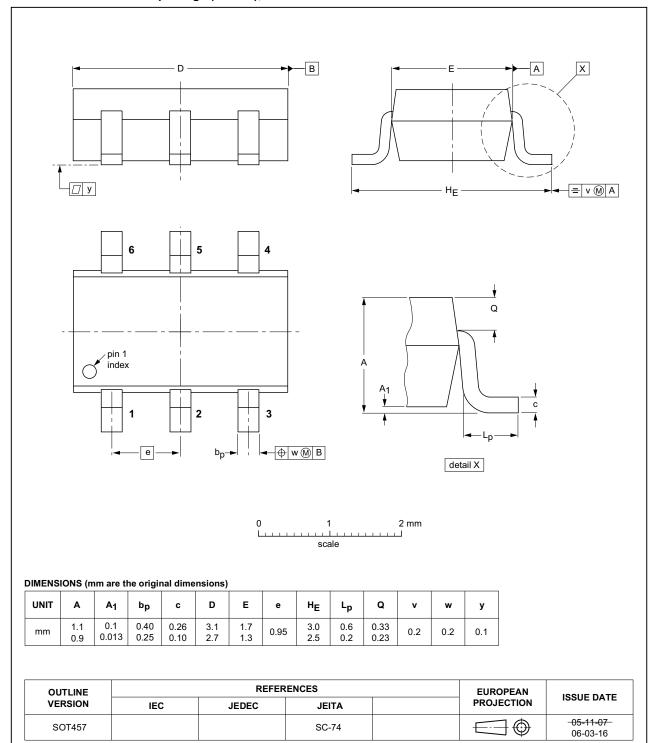


Fig 15. Package outline SOT457 (TSOP6)

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13. Revision history

Table 6. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
TEA1832TS v.1	20141216	Product data sheet	-	-

14. Legal information

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Document status[1][2]	Product status[3]	Definition
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GreenChip SMPS control IC

16. Contents

1	General description	. 1
2	Features and benefits	. 1
3	Applications	. 2
4	Ordering information	. 2
5	Block diagram	. 3
6	Pinning information	
6.1	Pinning	
6.2	Pin description	
7	Functional description	. 5
7.1	General control	. 5
7.2	Start-up and UnderVoltage LockOut (UVLO).	. 5
7.3	Supply management	. 6
7.4	External overtemperature protection	
	and mains detect input (pin PROTECT)	
7.5	Duty cycle control (pin CTRL)	
7.6	Slope compensation (pin CTRL)	
7.7	Overpower timer	
7.8 7.9	Current mode control (pin ISENSE)	
7.9 7.10	Overvoltage protection (pin ISENSE) Overvoltage protection (pin VCC)	
7.10	Output Short Circuit Protection (OSCP)	
7.12	Peak power, high-power and low-power	10
	operation	11
7.13	Overpower or high/low line compensation	12
7.14	Burst mode	13
7.15	Driver (pin DRIVER)	13
7.16	OverTemperature Protection (OTP)	13
8	Limiting values	13
9	Thermal characteristics	14
10	Characteristics	14
11	Application information	18
12	Package outline	19
13	Revision history	20
14	Legal information	21
14.1	Data sheet status	21
14.2	Definitions	21
14.3	Disclaimers	
14.4	Trademarks	22
15	Contact information	
16	Contents	23

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